

CERTIFICATION TEST REPORT

Report Number: 4790136523-E11V2

Applicant: SAMSUNG ELECTRONICS CO., LTD.

129 SAMSUNG-RO, YEONGTONG-GU, SUWON-SI,

GYEONGGI-DO, 16677, KOREA

Model: SM-N986B1/DS, SM-N986B1

FCC ID : A3LSMN986B1

EUT Description: GSM/WCDMA/LTE Phone + BT/BLE, DTS/UNII a/b/g/n/ac/ax, NFC,

WPT and UWB

Test Standard(s): FCC 47 CFR PART 1 SUBPART I

FCC 47 CFR PART 2 SUBPART J

Date Of Issue:

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Prepared by:

UL Korea, Ltd.

26th floor, 152, Teheran-ro, Gangnam-gu Seoul, 06236, Korea

Suwon Test Site: UL Korea, LTD. Suwon Laboratory 218 Maeyeong-ro, Yeongtong-gu Suwon-si, Gyeonggi-do, 16675, Korea

> TEL: (031) 337-9902 FAX: (031) 213-5433



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REPORT REVISION HISTORY

Rev.	Issue Date	Revisions	Revised By
V1	2021-11-05	Initial issue	Sungeun Lee
V2	2021-11-15	Updated to address TCB's question	Sungeun Lee

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1. ATTESTATION OF TEST RESULTS

COMPANY NAME: SAMSUNG ELECTRONICS CO., LTD.

EUT DESCRIPTION: GSM/WCDMA/LTE Phone + BT/BLE, DTS/UNII a/b/g/n/ac/ax,

NFC, WPT and UWB

MODEL: SM-N986B1/DS, SM-N986B1

SERIAL NUMBER: R3CR90Y67XD (RADIATED);

DATE TESTED: 2021-11-04;

APPLICABLE STANDARDS

STANDARD TEST RESULTS

FCC PART 1 SUBPART I FCC PART 2 SUBPART J

Complies

DATE: 2021-11-15

UL Korea, Ltd. tested the above equipment in accordance with the requirements set forth in the above standards. All indications of Pass/Fail in this report are opinions expressed by UL Korea, Ltd. based on interpretations and/or observations of test results. Measurement Uncertainties were not taken into account and are published for informational purposes only. The test results show that the equipment tested is capable of demonstrating compliance with the requirements as documented in this report.

Note: The results documented in this report apply only to the tested sample, under the conditions and modes of operation as described herein. This document may not be altered or revised in any way unless done so by UL Korea, Ltd. and all revisions are duly noted in the revisions section. Any alteration of this document not carried out by UL Korea, Ltd. will constitute fraud and shall nullify the document. This report must not be used by the client to claim product certification, approval, or endorsement by IAS, any agency of the Federal Government, or any agency of any government.

Approved & Released For UL Korea, Ltd. By:

Tested By:

Junwhan Lee Suwon Lab Engineer UL Korea, Ltd. Sungeun Lee Suwon Lab Engineer UL Korea, Ltd.

2. TEST METHODOLOGY

All calculations were made in accordance with FCC OET Bulletin 65 Edition 97-01.

3. FACILITIES AND ACCREDITATION

The test sites and measurement facilities used to collect data are located at 218 Maeyeong-ro, Yeongtong-gu, Suwon-si, Gyeonggi-do, 16675, Korea. Line conducted emissions are measured only at the 218 address. The following table identifies which facilities were utilized for radiated emission measurements documented in this report. Specific facilities are also identified in the test results sections.

218 Maeyeong-ro
Shield Room 1

UL Korea, Ltd. is accredited by IAS, Laboratory Code TL-637. The full scope of accreditation can be viewed at https://www.iasonline.org/wp-content/uploads/2017/05/TL-637-cert-New.pdf.

4. EQUIPMENT UNDER TEST

4.1. DESCRIPTION OF EUT

The EUT has WPT (Wireless Power Transfer) feature which has inductive charging coil to charge phone or watch. The charging frequency is between 110 kHz to 148 kHz, and the maximum power consumption is 9.0 W in charging status.

This report covers the Samsung models SM-N986B1/DS, SM-N986B1.

These models are identical in hardware except SM-N986B1/DS is supported dual SIM tray and SM-N986B1 has single SIM tray.

All series model was same hardware thus, SM-N986B1/DS(Dual SIM tray) was set for final test.

4.2. WORST-CASE CONFIGURATION

Test configuration	Description
DUT to Phone test configuration 1	Charging from Phone to DUT
DUT to Phone test configuration 2	Charging from Phone to DUT (TA Charging from DUT)
DUT to Phone test configuration 3 (Cross position)	Charging from Phone to DUT
DUT to Phone test configuration 4 (Cross position)	Charging from Phone to DUT (TA Charging from DUT)
DUT to Watch test configuration 5	Charging from Watch to DUT
DUT to Watch test configuration 6	Charging from Watch to DUT (TA Charging from DUT)

Note:

Configuration 2, 4 and 6 were tested with the worst case of configuration 1, 3 and 5.

4.3. KDB 680106 D01 v03 R01SECTION 5.b) EQUIPMENT APPROVAL CONSIDERATIONS

Requirement	Device
(1) Power transfer frequency is less than 1 MHz.	Yes. Operating Frequency is between 110kHz to 148 kHz.
(2) Output power from each primary coil is less than or equal to 15 watts.	Yes. Maximum power is 9.0 Watts.
(3) The transfer system includes only single primary and secondary coils. This includes charging systems that may have multiple primary coils and clients that are able to detect and allow coupling only between individual pairs of coils.	Yes.
(4) Client device is placed directly in contact with the transmitter.	Yes.
(5) Mobile exposure conditions only (portable exposure conditions are not covered by this exclusion).	Yes.
(6) The aggregate H-field strengths at 15 cm surrounding the device and 20 cm above the top surface from all simultaneous transmitting coils are demonstrated to be less than 50% of the MPE limit.	Yes. The aggregate field at 15 cm from the device are 23.44 % of the FCC H field limit.

4.4. DESCRIPTION OF TEST SETUP

SUPPORT EQUIPMENT & PERIPHERALS

SUPPROT EQUIPMENT & PERIPHERALS LIST							
Description	Description Manufacturer Model Serial Numver FCC ID						
Phone	Samsung Electronics Co., Ltd.	SM-G986B/DS	R3CMB0C70XN	A3LSMG986B			
Watch	Samsung Electronics Co., Ltd.	SM-R835F	RFAM90ZXFTF	A3LSMR835			
Traver Adapter	Samsung Electronics Co., Ltd.	EP-TA800	R37R38J4A28SE3	DoC			
USB Data Cable	Samsung Electronics Co., Ltd.	EP-DG980	N/A	-			

TEST SETUP

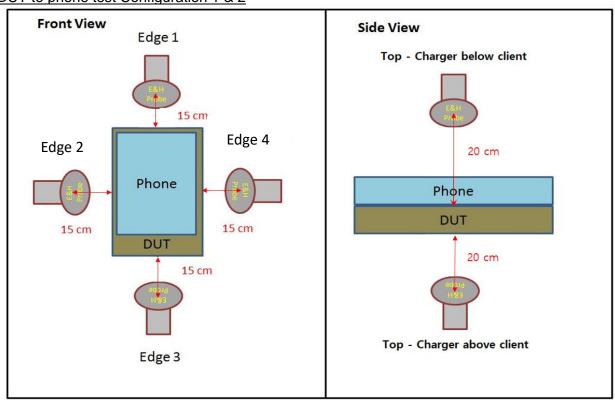
The following three modes are tested in test configurations;

Mode
Operating (SUPPORT Equipment, <10% Power Charging)
Operating (SUPPORT Equipment, 50~55% Power Charging)
Operating (SUPPORT Equipment, 90~95% Power Charging)

MEASUREMENT TEST SETUP

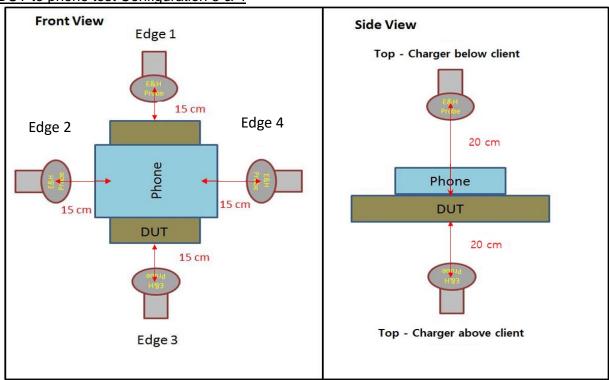
The measurement was taken using a probe placed 15 cm surrounding the device and 20 cm above the top surface of the EUT. Measurements were taken the top (charger below/above client) and all sides of the EUT per KDB680106 D01 v03 R01 and RF Exposure Procedures (Wireless Power Transfer) in TCB Workshop October, 2018.

DUT to phone test Configuration 1 & 2

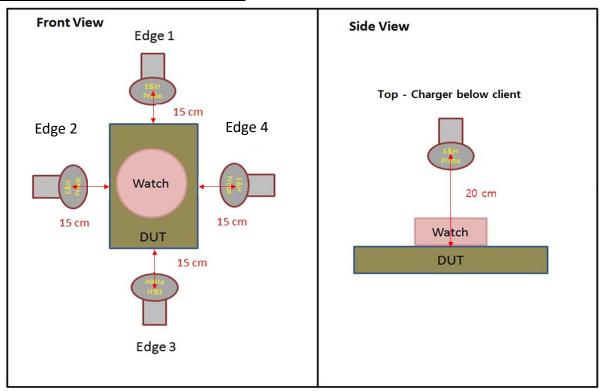


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DUT to phone test Configuration 3 & 4



DUT to Watch test Configuration 5 & 6



5. TEST AND MEASUREMENT EQUIPMENT

The following test and measurement equipment was used for the tests documented in this report;

Test Equipment List							
Description	Description Manufacturer Model S/N Cal Due						
E-H Field Analyzer	Narda	EHP-200AC	170WX91008	2022-08-06			

6. Maximum PERMISSIBLE RF EXPOSURE

FCC LIMITS AND SUMMARY 6.1.

6.1.1. FCC LIMITS

§ 1.1310 The criteria listed in Table 1 shall be used to evaluate the environmental impact of human exposure to radio-frequency (RF) radiation as specified in § 1.1307(b), except in the case of portable devices which shall be evaluated according to the provisions of § 2.1093 of this chapter.

TABLE 1-LIMITS FOR MAXIMUM PERMISSIBLE EXPOSURE (MPE)

Frequency range (MHz)	Electric field strength (V/m)	Magnetic field strength (A/m)	Power density (mW/cm²)	Averaging time (minutes)
(A) Lim	its for Occupational	/Controlled Exposur	es	
0.3–3.0	614	1.63	*(100)	6
3.0-30	1842/f	4.89/f	*(900/f ²)	6
30–300	61.4	0.163	1.0	6
300-1500			f/300	6
1500–100,000			5	6
(B) Limits	for General Populati	on/Uncontrolled Exp	oosure	
0.3–1.34	614	1.63	*(100)	30
1.34-30	824/f	2.19/f	*(180/f ²)	30

TABLE 1—LIMITS FOR MAXIMUM PERMISSIBLE EXPOSURE (MPE)—Continued

Frequency range (MHz)	Electric field strength (V/m)	Magnetic field strength (A/m)	Power density (mW/cm²)	Averaging time (minutes)
30–300	27.5	0.073	0.2 f/1500 1.0	30 30 30

f = frequency in MHz

^{* =} Plane-wave equivalent power density

^{* =} Plane-wave equivalent power density
NOTE 1 TO TABLE 1: Occupational/controlled limits apply in situations in which persons are exposed as a consequence of their
employment provided those persons are fully aware of the potential for exposure and can exercise control over their exposure.
Limits for occupational/controlled exposure also apply in situations when an individual is transient through a location where occupational/controlled limits apply provided he or she is made aware of the potential for exposure.

NOTE 2 TO TABLE 1: General population/uncontrolled exposures apply in situations in which the general public may be exposed, or in which persons that are exposed as a consequence of their employment may not be fully aware of the potential for

exposure or can not exercise control over their exposure.

6.2. **TEST RESULTS**

6.2.1. FCC RF EXPOSURE

H-FIELD MEASUREMENTS

Note: Peak measurement were performed. RMS values were calculated from the peak measurement.

Please refer to the formula for calculating the RMS values: [Field Strength x $\sqrt{\text{Duty Cycle}}$]. Additional test was performed in each Test mode by moving the probe surrounding the device to find the maximum exposure.

TEST results of DUT to phone test Configuration 1 & 2

FCC RF Exposure Result

Test Configuration	Test mode	Test distance	Test Position	H-Field Limit (A/m)	H-Field meas. data (A/m)
			Top - charger above client		0.1998
			Top - charger below client		0.2002
I			Edge 1		0.2011
	Operating Real Product (Power <10% charging)		Edge 2		0.1944
	(1 ower < 10 /0 onlarging)		Edge 3		0.1993
			Edge 4		0.1952
			Max	1.63	0.2011 0.2001 0.1996 0.2018
	Operating Real Product (Power 50~55% charging)		Top - charger above client		0.2001
		15 cm probe to edges of EUT and 20 cm probe to top surface of the EUT	Top - charger below client		0.1996
			Edge 1		0.2018
Configuration 1			Edge 2		0.1983
			Edge 3		0.1965
			Edge 4		0.1960
			Max		0.2018
			Top - charger above client		0.1994
			Top - charger below client		0.1990
			Edge 1		0.1974
	Operating Real Product (Power 90~95% charging)		Edge 2		0.1982
	(rower 90~95% charging)		Edge 3		0.1966
			Edge 4		0.1992
			Max		0.1994
Configuration	Operating Real Product		Edge 1		0.2022
Configuration 2	(Power 50~55% charging)		Max		0.2022

TEST results of DUT to phone test Configuration 3 & 4 **FCC RF Exposure Result**

Test Configuration	Test mode	Test distance	Test Position	H-Field Limit (A/m)	H-Field meas. data (A/m)
			Top - charger above client		0.2362
			Top - charger below client		0.1967
			Edge 1		0.1987
	Operating Real Product (Power <10% charging)		Edge 2		0.3782
	(1 ower < 10 % charging)		Edge 3		0.1994
			Edge 4 0.2140	0.2140	
			Max		0.3782
			Top - charger above client		0.2358
	Operating Real Product (Power 50~55% charging)	Top - charger below client Edge 1 Edge 2 and 20 cm probe to top surface of the EUT Top - charger below client Edge 2 Edge 3 Edge 4 Max Top - charger above client Top - charger below client	Top - charger below client	1.63	0.1982
			Edge 1		0.1980
Configuration 3			Edge 2		0.3804
			Edge 3		0.2007
			Edge 4		0.2153
			Max		0.3804
			Top - charger above client		0.2335
				0.2011	
			Edge 1		0.1992
	Operating Real Product (Power 90~95% charging)		Edge 2		0.3794
	(1 Ower 30-3070 Griarying)		Edge 3		0.2001
			Edge 4		0.2154
			Max		0.3794
Configuration 4	Operating Real Product		Edge 2		0.3820
Configuration 4	(Power 50~55% charging)		Max		0.3820

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TEST results of DUT to phone test Configuration 5 & 6 FCC RF Exposure Result

Test Configuration	Test mode	Test distance	Test Position	H-Field Limit (A/m)	H-Field meas. data (A/m)
Configuration 5	Operating Real Product (Power <10% charging)	15 cm probe to edges of EUT and 20 cm probe to top surface of the EUT	Top - charger below client	1.63	0.1983
			Edge 1		0.2001
			Edge 2		0.1944
			Edge 3		0.1988
			Edge 4		0.1975
			Max		0.2001
	Operating Real Product (Power 50~55% charging)		Top - charger below client		0.1992
			Edge 1		0.2010
			Edge 2		0.1963
			Edge 3		0.1982
			Edge 4		0.1971
			Max		0.2010
	Operating Real Product (Power 90~95% charging)		Top - charger below client		0.1990
			Edge 1		0.2011
			Edge 2		0.1992
			Edge 3		0.1974
			Edge 4		0.1983
			Max		0.2011
Configuration 6	Operating Real Product		Edge 1		0.2019
Configuration 6	(Power 90~95% charging)		Max		0.2019

6.2.2. FCC SUMMARY OF RESULTS

H-Field Limit					
FCC RF Exposure	Maximum meas data (A/m)	Percentage (%)			
1.63	0.382	23.44			

Conclusion:

H-Field result is less than 50% of the MPE limit.

END OF TEST REPORT